

SOT-23 Plastic-Encapsulate MOSFETs

BSS84 P-CHANNEL MOSFET

V_{(BR)DSS}	R_{D(on)MAX}	I_D
-50 V	8Ω@-10V	-0.13A
	10Ω@ -5V	

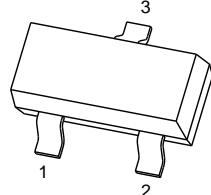
DESCRIPTION

These miniature surface mount MOSFETs reduce power loss conserve energy, making this device ideal for use in small power management circuitry.

FEATURE

- Energy Efficient
- Low Threshold Voltage
- High-speed Switching
- Miniature Surface Mount Package Saves Board Space

SOT-23



1. GATE
2. SOURCE
3. DRAIN

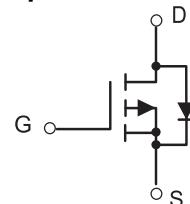
APPLICATION

- DC-DC converters, load switching, power management in portable and battery-powered products such as computers, printers, cellular and cordless telephones.

MARKING



Equivalent Circuit



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-50	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	-0.13	A
Pulsed Drain Current (note 1) @tp <10 μs	I _{DM}	-0.52	A
Power Dissipation	P _D	225	mW
Thermal Resistance from Junction to Ambient (note 2)	R _{θJA}	556	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55~+150	°C
Maximum Lead Temperature for Soldering Purposes , Duration for 5 Seconds	T _L	260	°C

MOSFET ELECTRICAL CHARACTERISTICS

T_a=25 °C unless otherwise specified

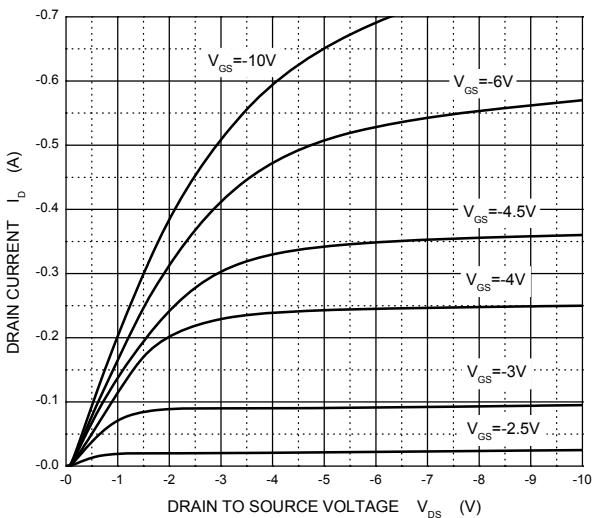
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-50			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-50V, V _{GS} = 0V			-15	μA
		V _{DS} =-25V, V _{GS} = 0V			-0.1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±20V, V _{DS} = 0V			±5	μA
Gate threshold voltage (note 3)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.9	-1.6	-2	V
Drain-source on-resistance (note 3)	R _{D(on)}	V _{GS} =-5V, I _D =-0.1A		5.8	10	Ω
		V _{GS} =-10V, I _D =-0.1A		4.5	8	Ω
Forward transconductance (note 1)	g _{FS}	V _{DS} =-25V; I _D =-100mA	50			mS
DYNAMIC CHARACTERISTICS (note 4)						
Input capacitance	C _{iss}	V _{DS} =5V, V _{GS} =0V, f =1MHz		30		pF
Output capacitance	C _{oss}			10		pF
Reverse transfer capacitance	C _{rss}			5		pF
SWITCHING CHARACTERISTICS (note 4)						
Turn-on delay time	t _{d(on)}	V _{DD} =-15V, R _L =50Ω, I _D =-2.5A		2.5		ns
Turn-on rise time	t _r			1		ns
Turn-off delay time	t _{d(off)}			16		ns
Turn-off fall time	t _f			8		ns
SOURCE-DRAIN DIODE CHARACTERISTICS						
Continuous Current	I _S				-0.13	A
Pulsed Current	I _{SM}				-0.52	A
Diode forward voltage (note 3)	V _{SD}	I _S =-0.13A, V _{GS} = 0V			-2.2	V

Notes :

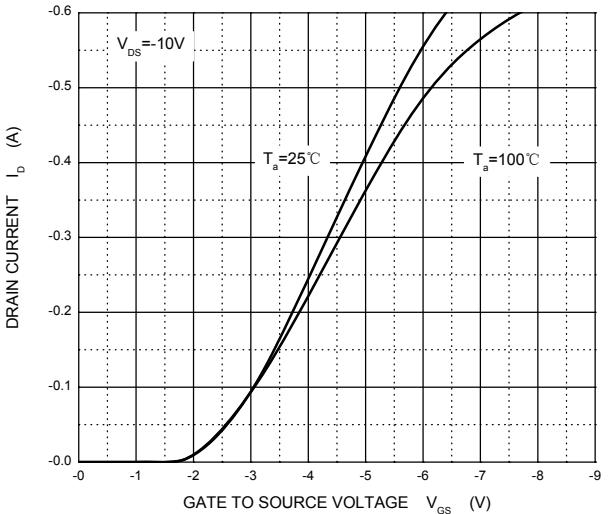
1. Repetitive rating : Pulse width limited by junction temperature.
2. Surface mounted on FR4 board , t≤10s.
3. Pulse Test : Pulse Width≤300μs, Duty Cycle≤2%.
4. Guaranteed by design, not subject to producing.

Typical Characteristics

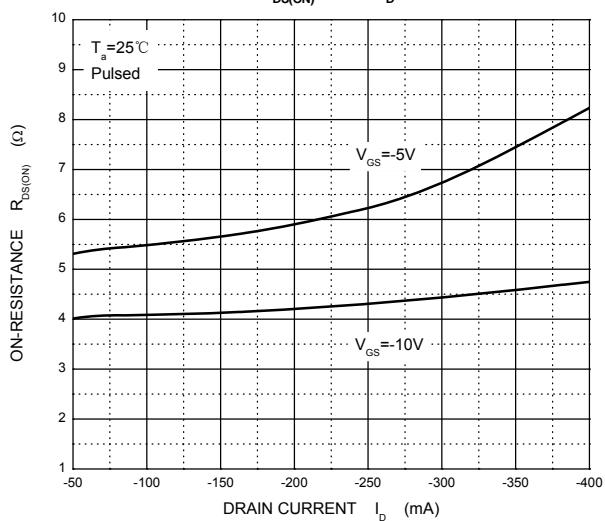
Output Characteristics



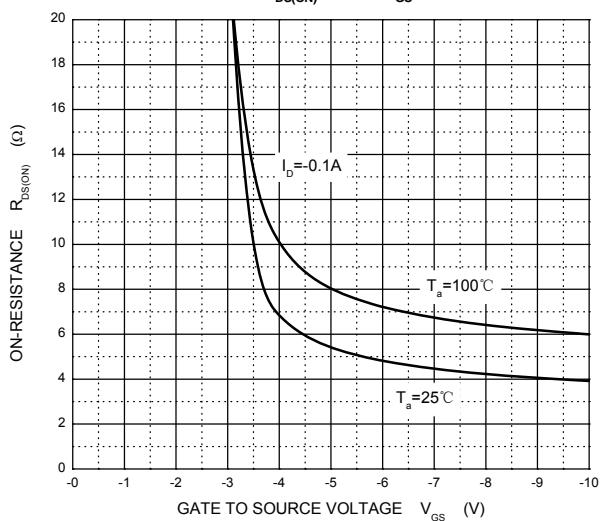
Transfer Characteristics



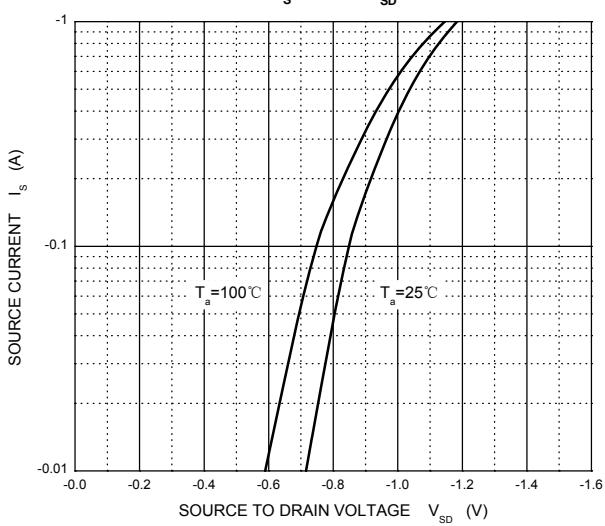
$R_{DS(ON)}$ — I_D



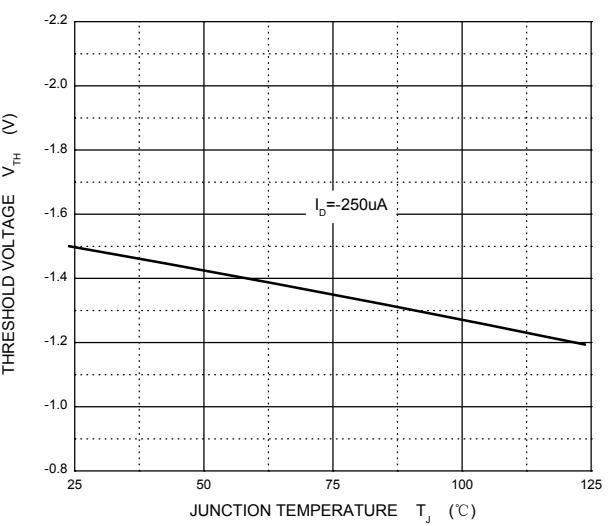
$R_{DS(ON)}$ — V_{GS}



I_s — V_{SD}



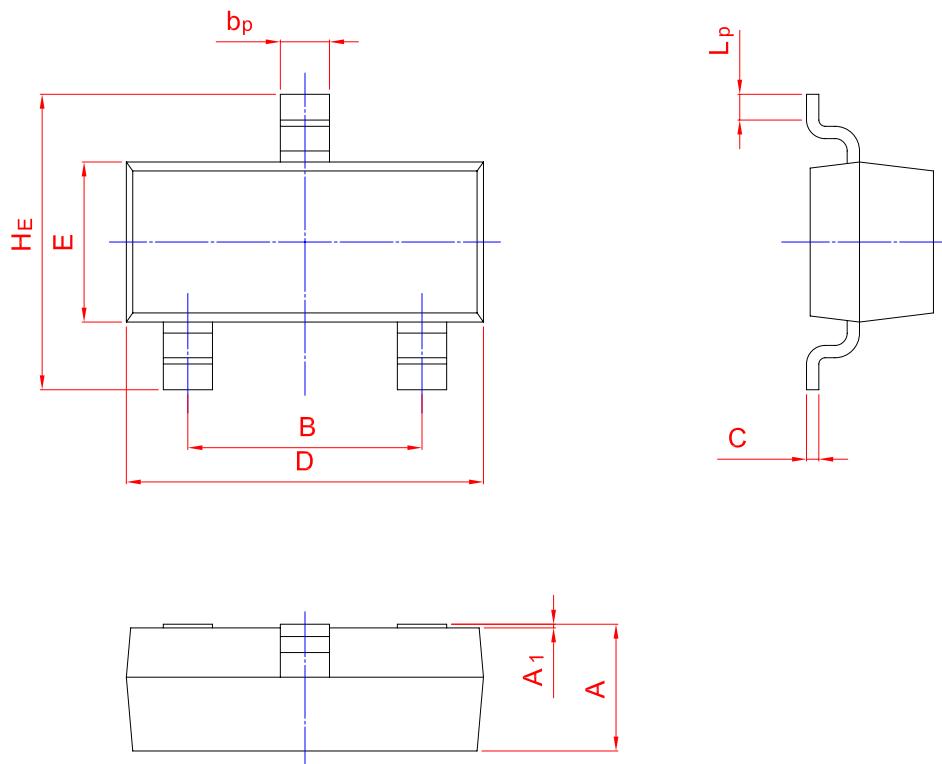
Threshold Voltage



PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b _p	C	D	E	H _E	A ₁	L _p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20

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